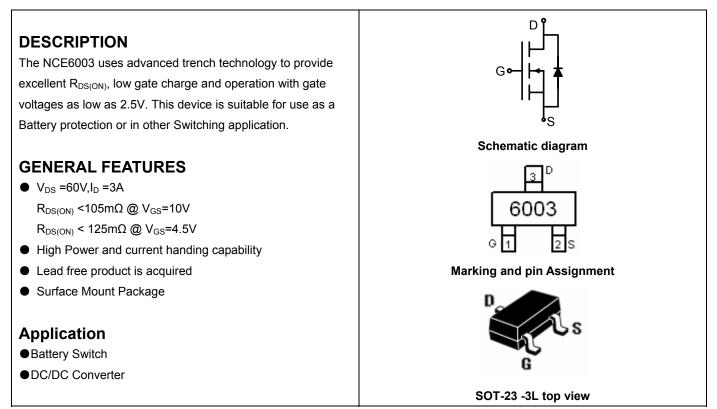




NCE N-Channel Enhancement Mode Power MOSFET



Package Marking And Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
6003	NCE6003	SOT-23-3L	Ø180mm	8 mm	3000 units

Absolute Maximum Ratings (TA=25°C unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	Vds	60	V
Gate-Source Voltage	Vgs	±20	V
Drain Current-Continuous	I _D	3	А
Drain Current-Pulsed (Note 1)	I _{DM}	10	А
Maximum Power Dissipation	PD	1.7	W
Operating Junction and Storage Temperature Range	TJ,TSTG	-55 To 150	°C

Thermal Characteristic

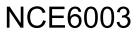
Thermal Resistance, Junction-to-Ambient (Note 2)R _{0JA} 73.5°C/W

Electrical Characteristics (TA=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit	
Off Characteristics							
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250µA	60	-	-	V	
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} =60V, V_{GS} =0V	-	-	1	μA	



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Gate-Body Leakage Current	I _{GSS}	V_{GS} =±20V, V_{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} ,I _D =250µA	1	1.4	3	V
Drain Courses On State Desistence	P	V _{GS} =10V, I _D =3A	-	-	105	mΩ
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =4.5V, I _D =3A	-	-	125	mΩ
Forward Transconductance	g fs	V _{DS} =15V,I _D =2A	3	-	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C _{lss}		-	247	-	PF
Output Capacitance	C _{oss}	V _{DS} =30V,V _{GS} =0V, F=1.0MHz	-	34	-	PF
Reverse Transfer Capacitance	C _{rss}		-	19.5	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	t _{d(on)}		-	6	-	nS
Turn-on Rise Time	tr	V _{DD} =30V,I _D =1.5A	-	15	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =10V, R_{GEN} =1 Ω	-	15	-	nS
Turn-Off Fall Time	t _f		-	10	-	nS
Total Gate Charge	Qg	\/ _20\/ L _2A	-	6	-	nC
Gate-Source Charge	Q _{gs}	V _{DS} =30V,I _D =3A, V _{GS} =4.5V	-	1	-	nC
Gate-Drain Charge	Q _{gd}	V _{GS} -4.5V	-	1.3	-	nC
Drain-Source Diode Characteristics			·	·	-	
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =3A	-	-	1.2	V
Diode Forward Current (Note 2)	I _S		-	-	3	А

Notes:

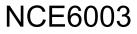
1. Repetitive Rating: Pulse width limited by maximum junction temperature.

2. Surface Mounted on FR4 Board, $t \le 10$ sec.

3. Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2%.

4. Guaranteed by design, not subject to production





TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS

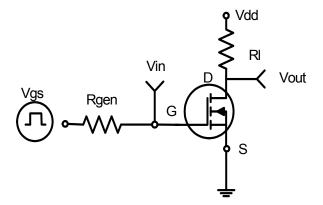
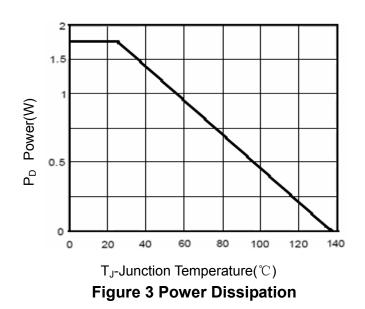
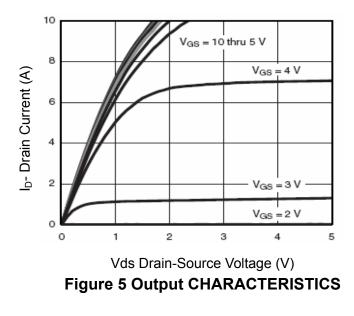
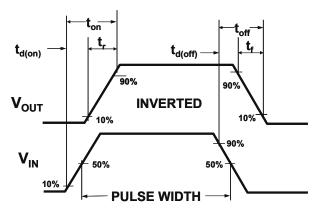


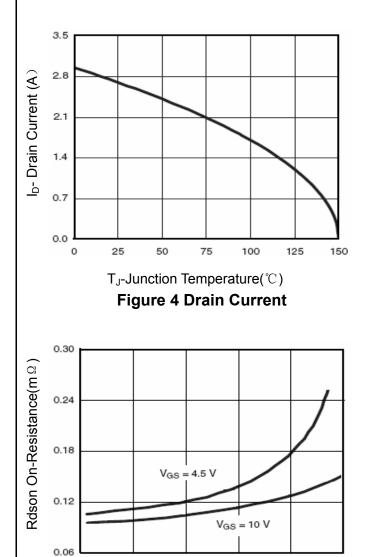
Figure 1:Switching Test Circuit











I_D- Drain Current (A) Figure 6 Drain-Source On-Resistance

6

8

4

2

0

10

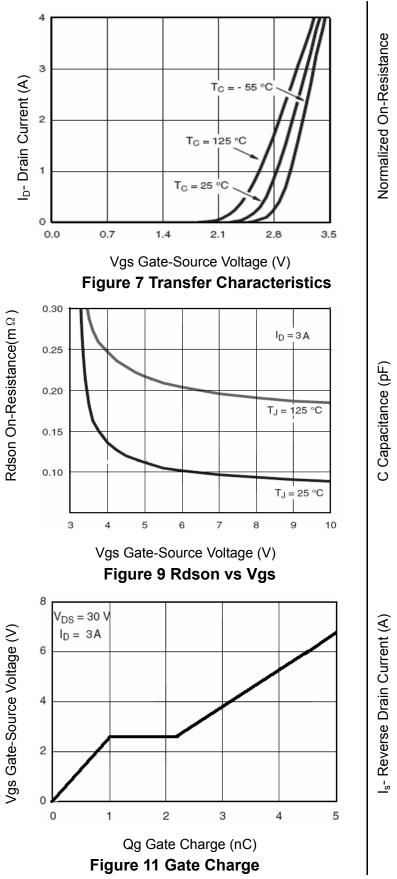


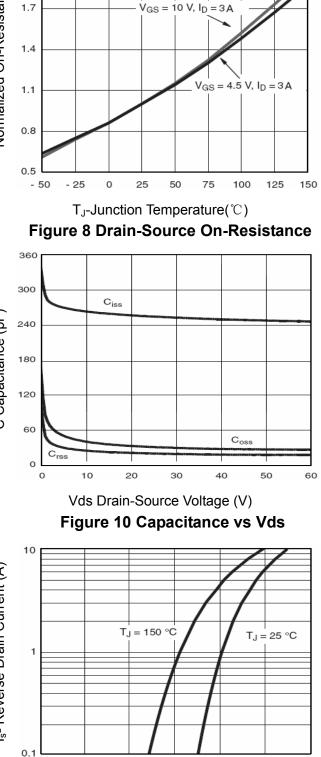
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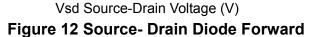
2.0



NCE6003







0.6

0.8

1.0

0.4

0.0

0.2

1.2

Pb Free Product



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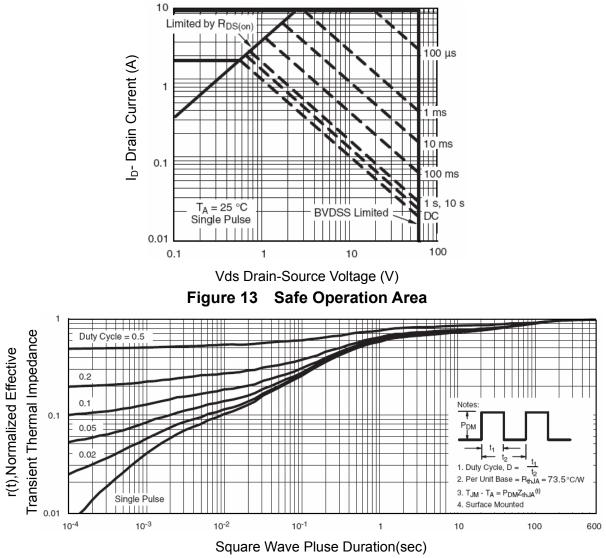
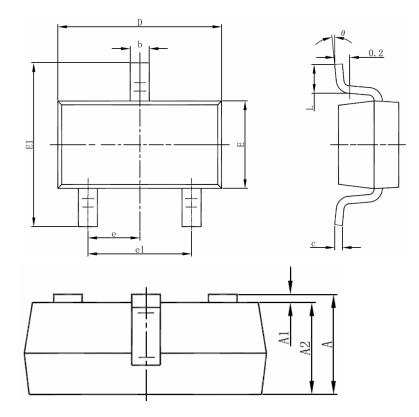


Figure 14 Normalized Maximum Transient Thermal Impedance





SOT-23-3L PACKAGE INFORMATION



Symbol	Dimensions Ir	n Millimeters	Dimensions In Inches		
0 yiiib0 i	Min	Max	Min	Max	
A	1.050	1.250	0.041	0.049	
A1	0.000	0.100	0.000	0.004	
A2	1.050	1.150	0.041	0.045	
b	0.300	0.500	0.012	0.020	
С	0.100	0.200	0.004	0.008	
D	2.820	3.020	0.111	0.119	
E	1.500	1.700	0.059	0.067	
E1	2.650	2.950	0.104	0.116	
е	0.950	(BSC)	0.037(BSC)		
e1	1.800	2.000	0.071	0.079	
L	0.300	0.600	0.012	0.024	
θ	0°	8°	0°	8°	

NOTES

1. All dimensions are in millimeters.

2. Tolerance ± 0.10 mm (4 mil) unless otherwise specified

3. Package body sizes exclude mold flash and gate burrs. Mold flash at the non-lead sides should be less than 5 mils.

4. Dimension L is measured in gauge plane.

5. Controlling dimension is millimeter, converted inch dimensions are not necessarily exact.



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